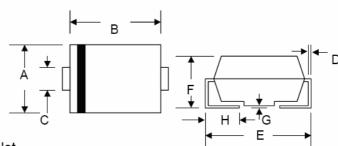


## Technical Data Data Sheet N0568, Rev. -Features

### **Green Products**

#### Glass Passivated Die Construction

- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Low Power Loss
- Built-in Strain Relief
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



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IVIC	CIIG	11100		ıu

- Case: Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)
- Marking: Part Name, Date Code

SMB/DO-214AA						
Dim	Min	Max	Min	Max		
Α	3.30	3.94	0.130	0.155		
В	4.06	4.70	0.160	0.185		
С	1.91	2.11	0.075	0.083		
D	0.152	0.305	0.006	0.012		
Е	5.08	5.59	0.2	0.220		
F	2.13	2.44	0.084	0.096		
G	0.051	0.203	0.002	0.008		
Н	0.76	1.27	0.029	0.05		
	in mm		ln i	nch		

## **Marking Diagram:**

Where XXXXX is YYWWL



 S1AB
 = Part Name

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Ordering Information**

Package	Shipping
SMB (Ph-Fron)	3000pcs / reel
	<del>_</del>

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

<sup>•</sup> Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

<sup>•</sup> FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



Technical Data Data Sheet N0568, Rev. - **Green Products** 

# Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic		Symbol	S1AB	S1BB	S1DB	S1GB	S1JB	S1KB	S1MB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		VRRM VRWM VR	50	100	200	400	600	800	1000	٧
RMS Reverse Voltage		VR(RMS)	35	70	140	280	420	560	700	٧
Average Rectified Output Current @T <sub>L</sub> = 100°C		lo	1.0					Α		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	30					А		
Forward Voltage	@I <sub>F</sub> = 1.0A	VFM	1.10				V			
Peak Reverse Current At Rated DC Blocking Voltage	@T <sub>A</sub> = 25°C @T <sub>A</sub> = 125°C	IRM				5.0 200				μA
Reverse Recovery Time (Note 1)		trr	2.5					μS		
Typical Junction Capacitance (Note 2)		Cj	15				pF			
Typical Thermal Resistance (Note 3)		$R_{\theta}$ JL	30				K/W			
Operating and Storage Temperature Range		Тј, Тѕтс	-65 to +175				°C			

Note: 1. Measured with  $I_F$  = 0.5A,  $I_R$  = 1.0A,  $I_{rr}$  = 0.25A,

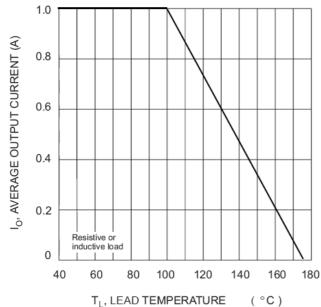
2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.

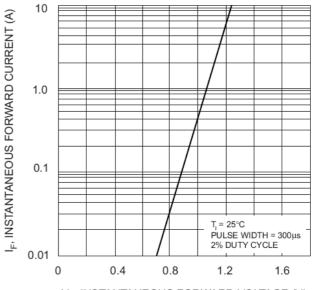
3. Mounted on P.C. Board with 8.0mm<sup>2</sup> land area.

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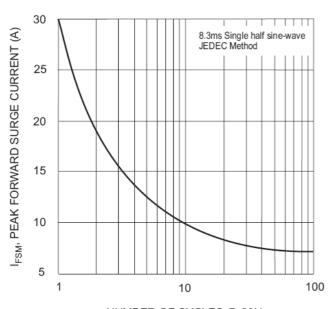
## **Green Products**

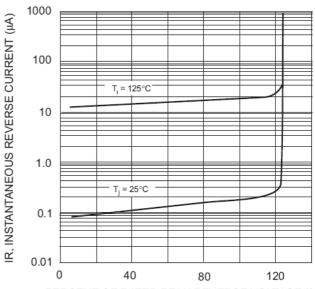




T<sub>L</sub>, LEAD TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve

V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics





NUMBER OF CYCLES @ 60Hz Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 4 Typical Reverse Characteristics

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**Green Products** 

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